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			•	Application Number	Not Yet Assigned 10/616, 711	
INFORMATION DISCLOSURE				Filing Date	Gencurrently Herewith 7/10/03	
S	STATEMENT BY APPLICANT			First Named Inventor	Won-Ho Lee	
				Art Unit .	NA 2878	
	(use as many sheets as necessary)			Examiner Name	Not-Yet Assigned Le_	
Sheet	1	of	1	Attorney Docket Number	29926/39500	

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1	C1	Fujieda et al., "Dependence of Si PH Junction Perimeter Leakage on the Channel-Stop Boron Dose and Interlayer Material," <i>IEEE Electron Device Letters, Vol. 20, No. 8,</i> 418-420 (August 1999).			
į	C2	Morris et al., "An Accurate and Efficient Model for Boron Implants through Thin Oxide Layers into Single-Crystal Silicon," <i>IEEE Transactions on Semiconductor Manufacturing 8(4,)</i> 408-413 (November 1995).			
1	СЗ	Son et al., "Blanket Tilt Implanted Shallow Trench Isolation (BTI0STI) Process for Enhanced Dram Retention Time Characteristics," IEEE 122-124 (1999).			
1	C4	Walther et al., "Dopant Channeling as a Function of Implant Angle for Low Energy Applications," IEEE 126-129 (1999).			

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